Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.380 inches
Overall Diameter:
0.505 inches
Internal Configuration: Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
20.00 amperes drain current horsepower metric
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector outside diameter
Maximum Operating Tempurature Per Measurement Point:
105.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0